

## HM50N06IA-VB Datasheet

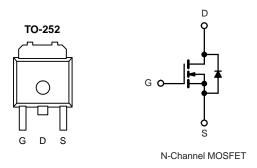
# N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	V <sub>DS</sub> (V) R <sub>DS(on)</sub> (Ω)		
60	0.010 at V <sub>GS</sub> = 10 V	58	
00	0.013 at V <sub>GS</sub> = 4.5 V	56	



- 175 °C Junction Temperature
- Trench Power MOSFET
- Material categorization:





Parameter		Symbol	Limit	Unit
Gate-Source Voltage		V <sub>GS</sub>	± 20	V
	T <sub>C</sub> = 25 °C	1-	58	
Continuous Drain Current (T <sub>J</sub> = 175 °C) <sup>b</sup>	T <sub>C</sub> = 100 °C	I <sub>D</sub>	48 <sup>a</sup>	
Pulsed Drain Current		I <sub>DM</sub>	100	А
Continuous Source Current (Diode Conduction)		۱ <sub>S</sub>	50 <sup>a</sup>	-
Avalanche Current		I <sub>AS</sub>	50	
Single Avalanche Energy (Duty Cycle $\leq$ 1 %)	L = 0.1 mH	E <sub>AS</sub>	125	mJ
Maximum Dawar Dissingtion	T <sub>C</sub> = 25 °C	P	136	w
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	• P <sub>D</sub> —	3 <sup>b</sup> , 8.3 <sup>b, c</sup>	VV
Operating Junction and Storage Temperature Range	•	T <sub>J</sub> , T <sub>stq</sub>	- 55 to 175	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	$t \le 10 \text{ sec}$	- R <sub>thJA</sub>	15	18	°C/W
Maximum Junction-to-Ambient*	Steady State		40	50	
Maximum Junction-to-Case		R <sub>thJC</sub>	0.85	1.1	

Notes:

a. Package limited.

b. Surface mounted on 1" x 1" FR4 board.

c. t  $\leq$  10 s.

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<u></u>	Unit	
	<u> </u>	
	V	
3	v	
± 100	nA	
1		
50	μA	
250		
	А	
	Ω	
	S	
	pF	
70		
	nC	
20		
25		
50	ns	
30		
60	А	
1.5	V	
100	ns	
	30 60 1.5	

#### **SPECIFICATIONS** (T<sub>1</sub> = 25 °C, unless otherwise noted)

Notes:

a. For design aid only; not subject to production testing.

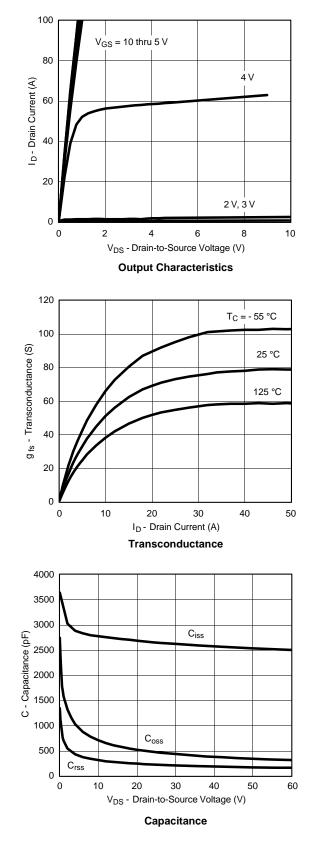
b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

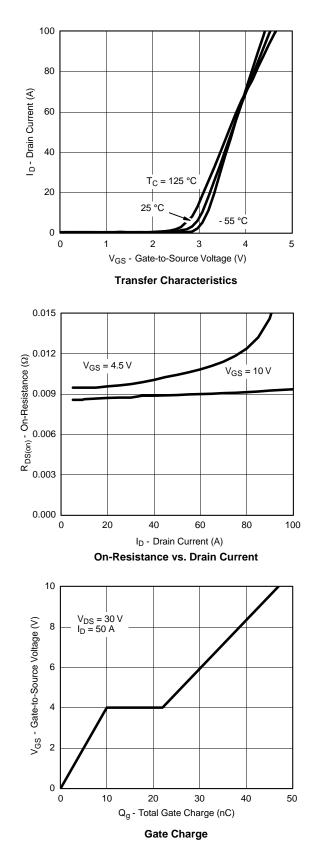
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



#### TYPICAL CHARACTERISTICS (25 °C unless noted)

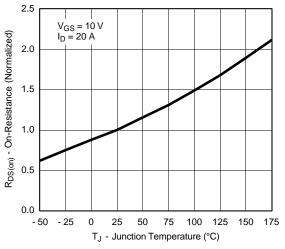




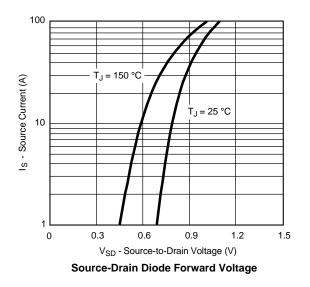
服务热线:400-655-8788



### TYPICAL CHARACTERISTICS (25 °C unless noted)

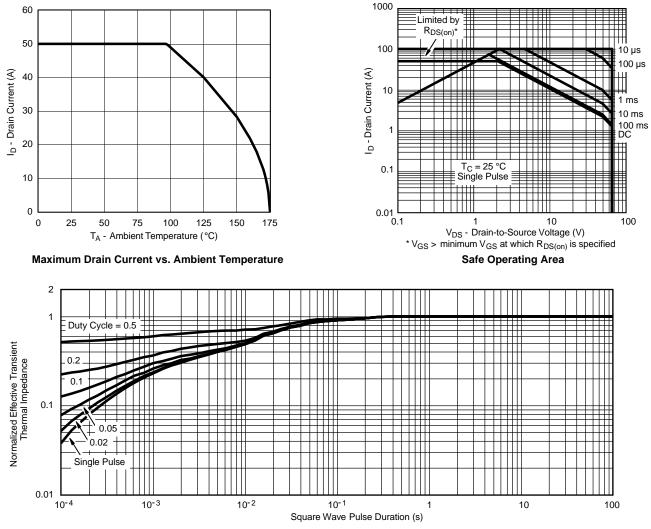


**On-Resistance vs. Junction Temperature** 





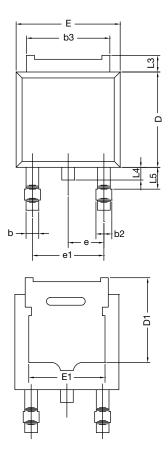
#### **THERMAL RATINGS**

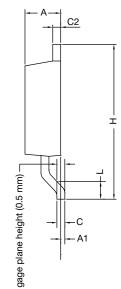


Normalized Thermal Transient Impedance, Junction-to-Case



## **TO-252AA CASE OUTLINE**





	MILLIMETERS		INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	5.21	-	0.205	-	
E	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090 BSC		
e1	4.56	4.56 BSC		0.180 BSC	
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	
ECN: X12-( DWG: 5347	0247-Rev. M,	24-Dec-12			

#### Note

• Dimension L3 is for reference only.



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